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FQU3N50C **N-Channel QFET® MOSFET**

500 V, 2.5 A, 2.5 Ω

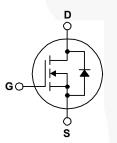
Description

This N-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, active power factor correction (PFC), and electronic lamp ballasts.

Features

- 2.5 A, 500 V, $R_{DS(on)}$ = 2.5 Ω (Max.) @ V_{GS} = 10 V, I_D = 1.25 A
- Low Gate Charge (Typ. 10 nC)
- Low Crss (Typ. 8.5 pF)
- 100% Avalanche Tested





Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol	Parameter		FQU3N50CTU	Unit	
V _{DSS}	Drain-Source Voltage		500	V	
I _D	Drain Current - Continuous (T _C = 25°C)		2.5	A	
	- Continuous (T _C = 100°C)		1.5	А	
I _{DM}	Drain Current - Pulsed	(Note 1)	10	А	
V _{GSS}	Gate-Source Voltage		± 30	V	
E _{AS}	Single Pulsed Avalanche Energy (Note 2)		200	mJ	
I _{AR}	Avalanche Current		2.5	A	
E _{AR}	Repetitive Avalanche Energy (Note		3.5	mJ	
dv/dt	Peak Diode Recovery dv/dt (Note 3)		4.5	V/ns	
P _D	Power Dissipation ($T_C = 25^{\circ}C$)		35	W	
	- Derate above 25°C		0.28	W/°C	
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +150	°C	
Τ _L	Maximum lead temperature for soldering, 1/8" from case for 5 seconds		300	°C	

Thermal Characteristics

FQU3N50C Rev C1

Symbol	Parameter	FQU3N50CTU	Unit
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction-to-Case, Max.	3.5	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient (Minimum Pad of 2-oz Copper), Max.	110	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient (*1 in2 Pad of 2-oz Copper), Max.	50	°C/W

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Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FQU3N50CTU	FQU3N50C	IPAK	Tube	N/A	N/A	75 units

Electrical Characteristics T_c = 25°C unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Charac	teristics					
BV _{DSS}	Drain-Source Breakdown Voltage	V_{GS} = 0 V, I _D = 250 µA	500			V
ΔBV_{DSS} / ΔT_{J}	Breakdown Voltage Temperature Coefficient			0.7		V/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 500 V, V _{GS} = 0 V			1	μA
		V_{DS} = 400 V, T_{C} = 125°C			10	μA
I _{GSSF}	Gate-Body Leakage Current, Forward	V _{GS} = 30 V, V _{DS} = 0 V			100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse	V_{GS} = -30 V, V_{DS} = 0 V		-	-100	nA
On Charact	teristics					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \ \mu A$	2.0		4.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	V _{GS} = 10 V, I _D = 1.25 A		2.1	2.5	Ω
9 _{FS}	Forward Transconductance	V _{DS} = 40 V, I _D = 1.25 A		1.5		S
Dynamic Cl	haracteristics					
C _{iss}	Input Capacitance	$V_{DS} = 25 V, V_{GS} = 0 V,$		280	365	pF
C _{oss}	Output Capacitance	f = 1.0 MHz	-	50	65	pF
C _{rss}	Reverse Transfer Capacitance			8.5	11	pF
Switching C	Characteristics					
t _{d(on)}	Turn-On Delay Time	V _{DD} = 250 V, I _D = 2.5A,		10	30	ns
t _r	Turn-On Rise Time	R _G = 25 Ω		25	60	ns
t _{d(off)}	Turn-Off Delay Time	-		35	80	ns
t _f	Turn-Off Fall Time	- (Note 4)		25	60	ns
Qg	Total Gate Charge	V _{DS} = 400 V, I _D = 2.5A,		10	13	nC
Q _{gs}	Gate-Source Charge	– V _{GS} = 10 V		1.5		nC
Q _{gd}	Gate-Drain Charge	(Note 4)		5.5		nC
Drain-Source	ce Diode Characteristics and Maximum Ratings	6			1	
I _S	Maximum Continuous Drain-Source Diode Fo	rward Current			2.5	А
I _{SM}	Maximum Pulsed Drain-Source Diode Forward Current				10	А
V _{SD}	Drain-Source Diode Forward Voltage	V _{GS} = 0 V, I _S = 2.5 A			1.4	V
t _{rr}	Reverse Recovery Time	V _{GS} = 0 V, I _S = 3 A,		170		ns
Q _{rr}	Reverse Recovery Charge	dI _F / dt = 100 A/μs		0.7		μC

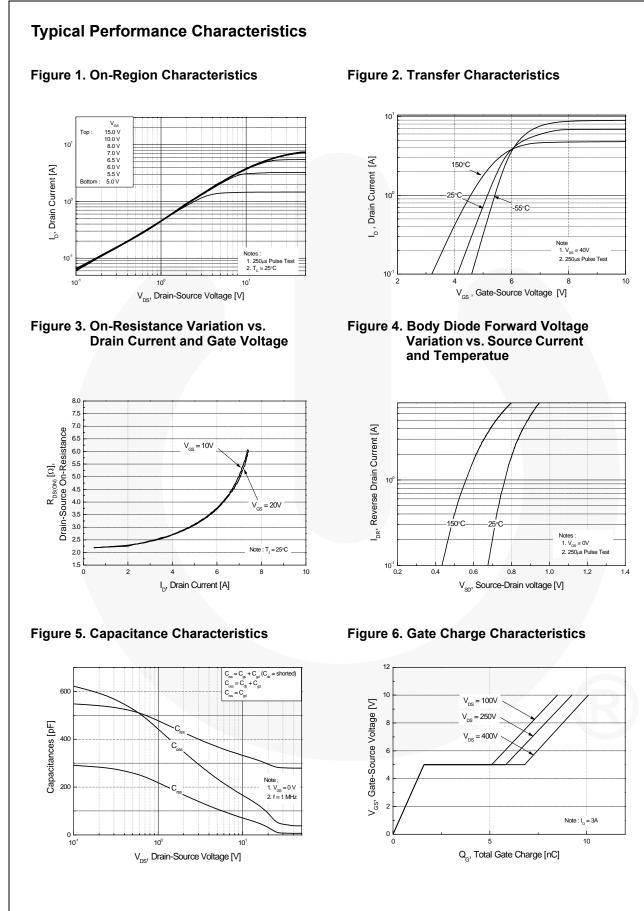
NOTES:

1. Repetitive rating : pulse-width limited by maximum junction temperature.

2. L = 58 mH, I_{AS} = 2.5 A, V_{DD} = 50 V, R_G = 25 $\Omega,$ starting $\mbox{ T}_{J}$ = 25°C.

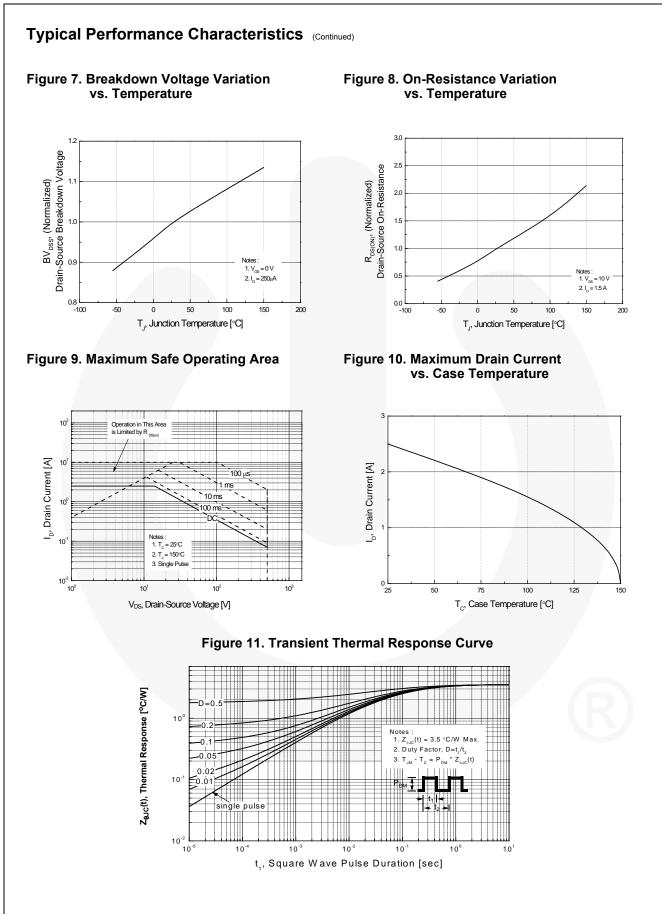
3. I_{SD} \leq 2.5 A, di/dt ${\leq}200$ A/µs, V_{DD} ${\leq}$ BV_{DSS,} starting $~T_{J}$ = 25°C.

4. Essentially independent of operating temperature.

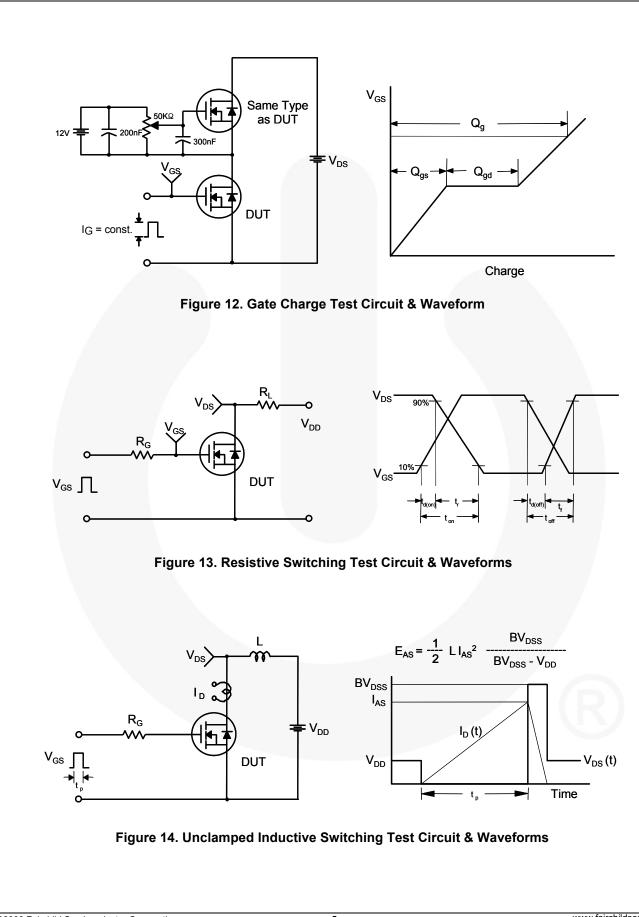


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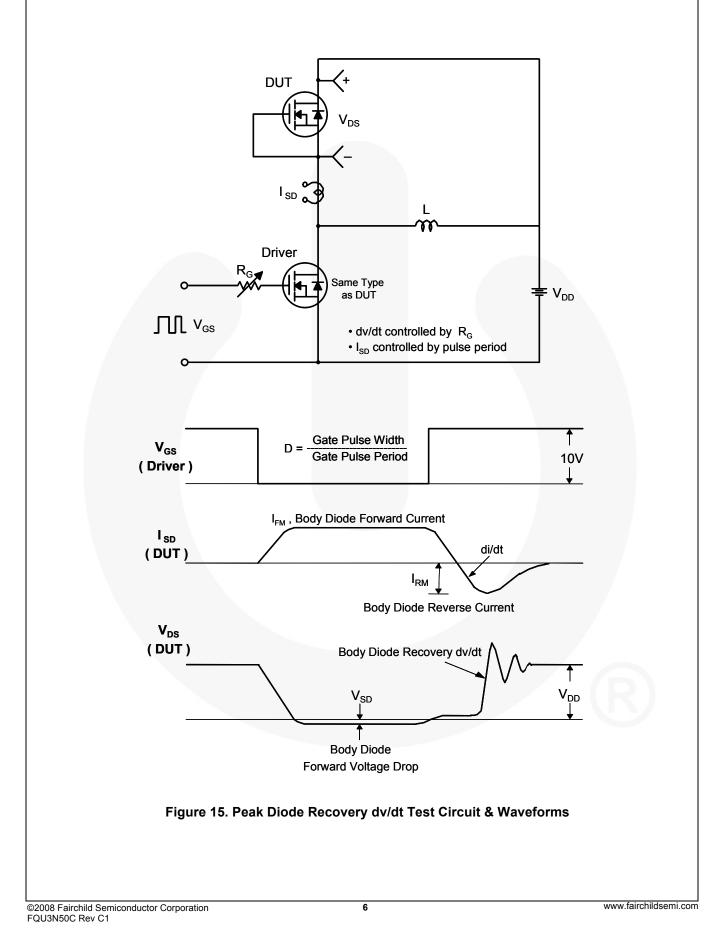
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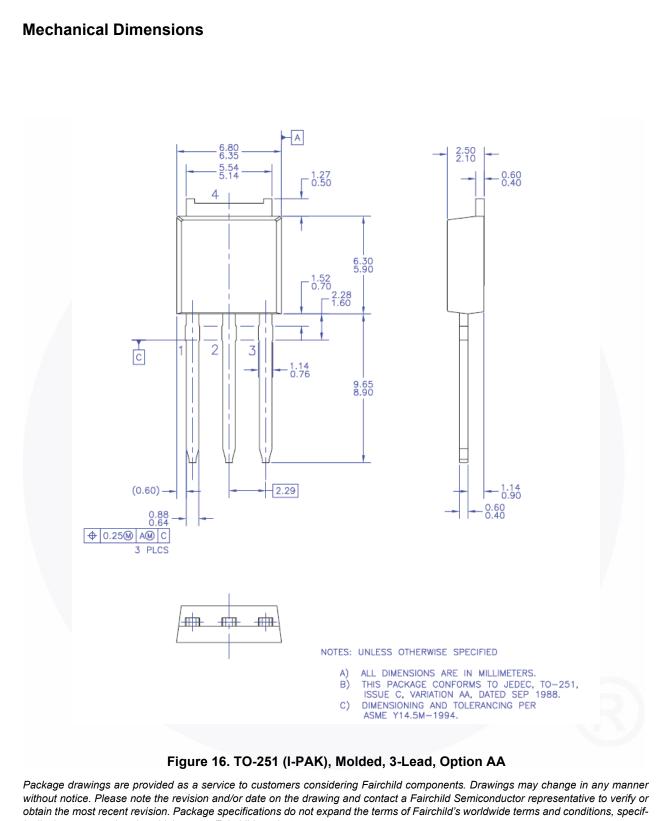


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